

2SC3934

Silicon NPN epitaxial planar type

For high-frequency wide-band low-noise amplification

■ Features

- High transition frequency f_T
- S-Mini type package, allowing downsizing of the equipment and automatic insertion through the tape packing and the magazine packing

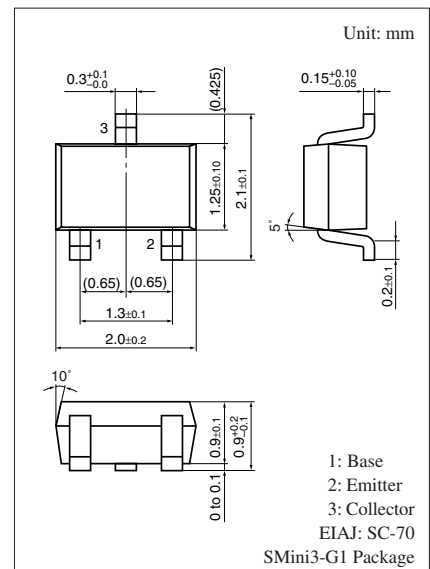
■ Absolute Maximum Ratings $T_a = 25^\circ\text{C}$

Parameter	Symbol	Rating	Unit
Collector-base voltage (Emitter open)	V_{CBO}	15	V
Collector-emitter voltage (Base open)	V_{CEO}	12	V
Emitter-base voltage (Collector open)	V_{EBO}	2.5	V
Collector current	I_C	30	mA
Peak collector current	I_{CP}	50	mA
Collector power dissipation	P_C	150	mW
Junction temperature	T_j	150	$^\circ\text{C}$
Storage temperature	T_{stg}	-55 to +150	$^\circ\text{C}$

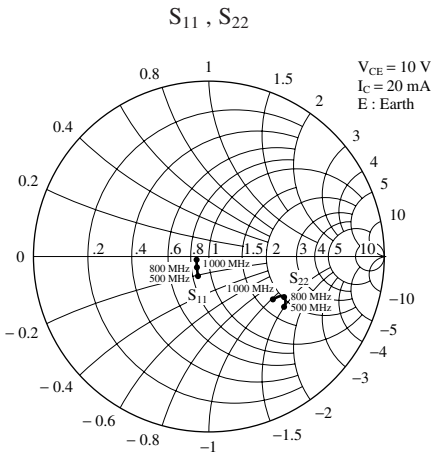
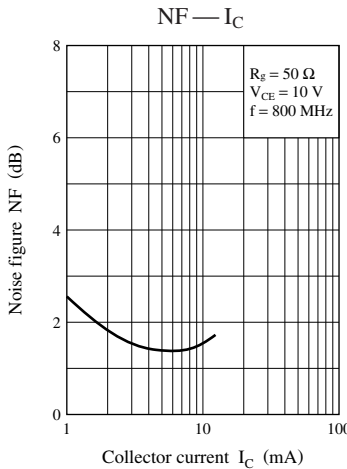
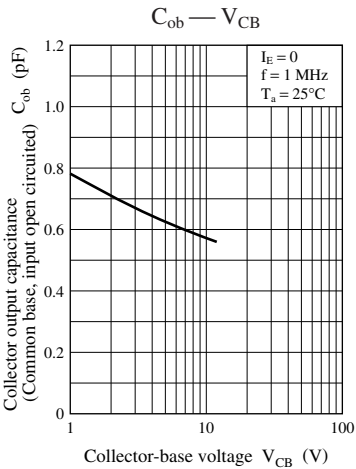
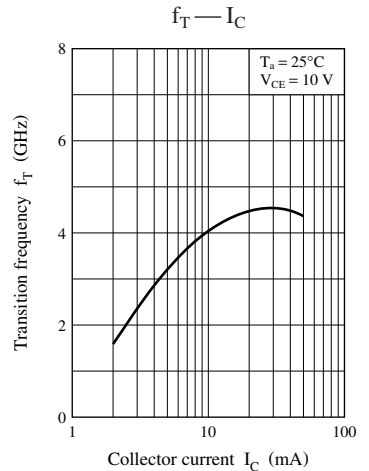
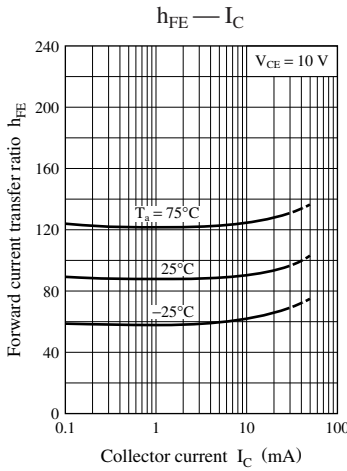
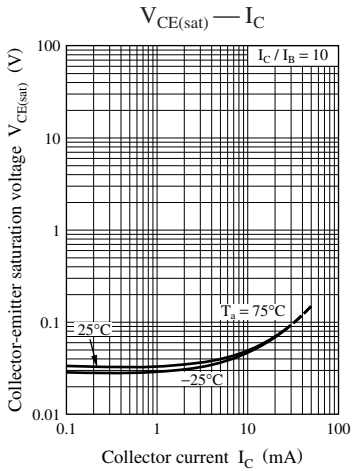
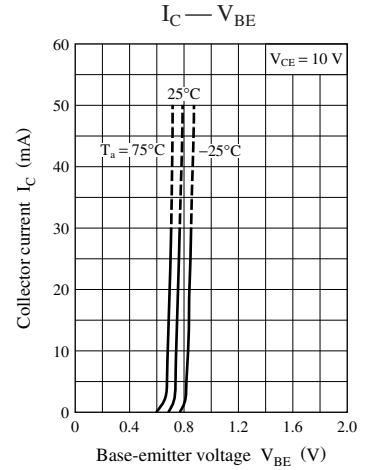
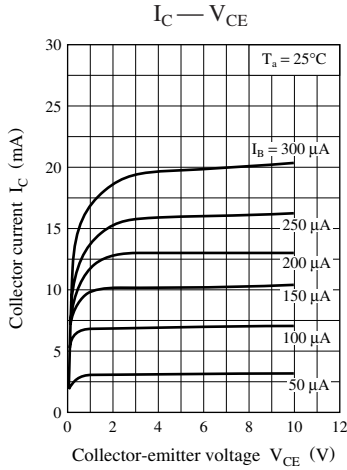
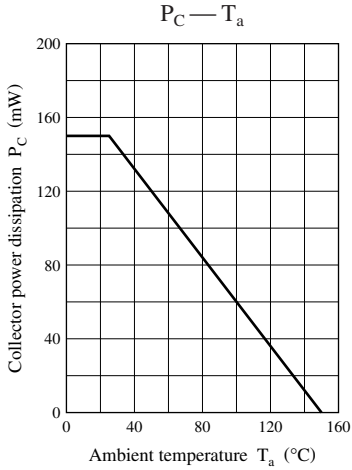
■ Electrical Characteristics $T_a = 25^\circ\text{C} \pm 3^\circ\text{C}$

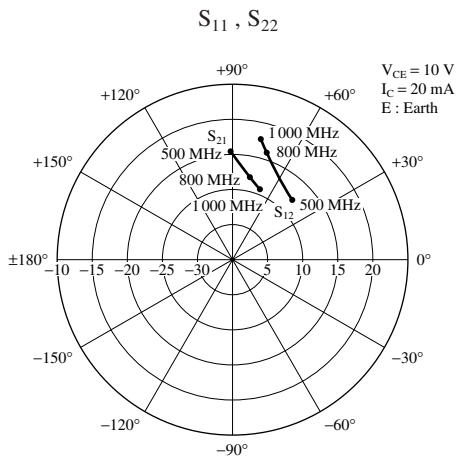
Parameter	Symbol	Conditions	Min	Typ	Max	Unit
Collector-base cutoff current (Emitter open)	I_{CBO}	$V_{CB} = 10\text{ V}, I_E = 0$			100	nA
Emitter-base cutoff current (Collector open)	I_{EBO}	$V_{EB} = 2\text{ V}, I_C = 0$			1	μA
Forward current transfer ratio	h_{FE}	$V_{CE} = 10\text{ V}, I_C = 10\text{ mA}$	40			—
Transition frequency	f_T	$V_{CE} = 10\text{ V}, I_C = 10\text{ mA}, f = 0.8\text{ GHz}$		4.5		GHz
Collector output capacitance (Common base, input open circuited)	C_{ob}	$V_{CB} = 10\text{ V}, I_E = 0, f = 1\text{ MHz}$			1.2	pF
Forward transfer gain	$ S_{21e} ^2$	$V_{CE} = 10\text{ V}, I_C = 20\text{ mA}, f = 0.8\text{ GHz}$	9	12		dB
Maximum unilateral power gain	G_{UM}	$V_{CE} = 10\text{ V}, I_C = 20\text{ mA}, f = 0.8\text{ GHz}$	12	14		dB
Noise figure	NF	$V_{CE} = 10\text{ V}, I_C = 5\text{ mA}, f = 0.8\text{ GHz}$		1.3	2.5	dB

Note) Measuring methods are based on JAPANESE INDUSTRIAL STANDARD JIS C 7030 measuring methods for transistors.



Marking Symbol: 1U





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